

Features

- High Dense Cell Design for Extremely Low R_{DS(ON)}
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

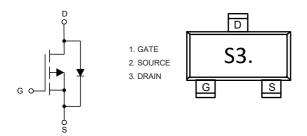
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 96°C/W Junction to Ambient (Note 2)

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	-30	V	
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _A =25°C		-3	Α	
	T _A =100°C	l _D	-1.9		
Pulsed Drain Current (Note 3)		I _{DM}	-12	Α	
Total Power Dissipation (Note 4)		P _D	1.3	W	

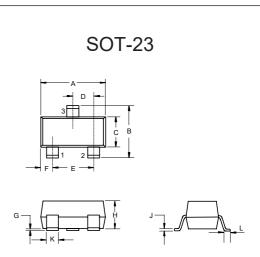
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code

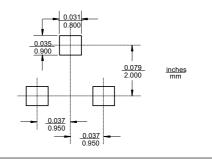


P-CHANNEL MOSFET



	DIMENSIONS				
DIM N	INC	INCHES		М	NOTE
	MIN	MAX	MIN	MAX	NOIL
Α	0.110	0.120	2.80	3.04	
В	0.083	0.104	2.10	2.64	
С	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
Е	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
Н	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



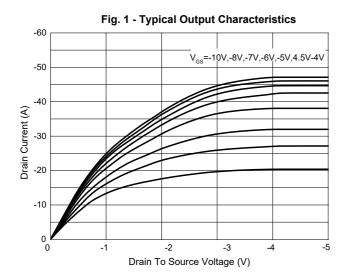


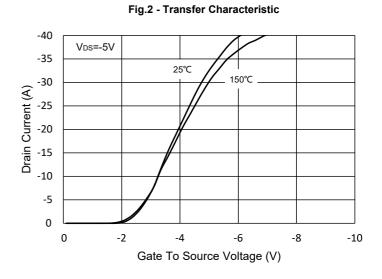
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

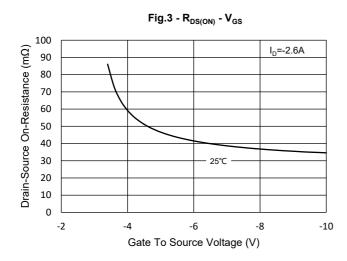
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics	1		-		1	1	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-10μA	-30			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA	
Gate-Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.5	-3	V	
Drain Cauras On Basistanas	_	V _{GS} =-10V, I _D =-2.6A		37	55	mΩ	
Drain-Source On-Resistance	$R_{DS(on)}$	V _{GS} =-4.5V, I _D =-2A		50	68		
Gate Resistance	R _g	f=1 MHz, Open drain		19		Ω	
Forward Tranconductance	g FS	V _{DS} =-5V, I _D =-1.5A		5.8		S	
Diode Characteristics							
Continuous Body Diode Current	Is				-3	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-1.25A			-1.2	V	
Reverse Recovery Time	t _{rr}	I _F =-4.1A,di/dt=100A/μs		29		ns	
Reverse Recovery Charge	Q _{rr}	1;=-4.1A,α//α(=100A/μ5		11		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			493			
Output Capacitance	C _{oss}	V _{DS} =15V,V _{GS} =0V,f=1MHz		75		pF	
Reverse Transfer Capacitance	C _{rss}			58		1	
Total Gate Charge	Q_g			8.9			
Gate-Source Charge	Q_{gs}	V _{DS} =-15V,V _{GS} =-10V,I _D =-4.1A		1.5		nC	
Gate-Drain Charge	Q_{gd}			2.2			
Turn-On Delay Time	t _{d(on)}			8.4			
Turn-On Rise Time	t _r	V _{DD} =-15V, V _{GS} =-10V,		3.9		20	
Turn-Off Delay Time	t _{d(off)}	$R_G=6\Omega$, $I_D=-4.1A$		31		- ns -	
Turn-Off Fall Time	t _f			16			

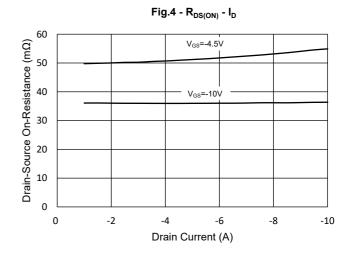


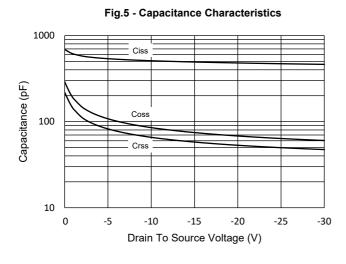
Curve Characteristics

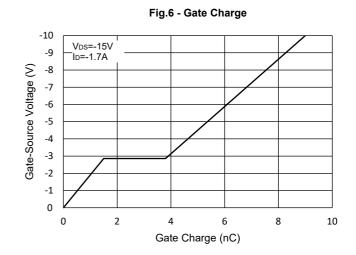














Curve Characteristics

Fig.7 - Normalized Threshold Voltage

1.2

1.0

0.8

0.8

0.8

0.9

0.04

1.0

0.2

(#)

0.0

-50

-50

-25

0

25

50

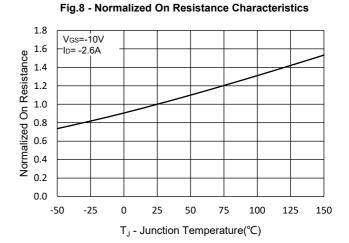
75

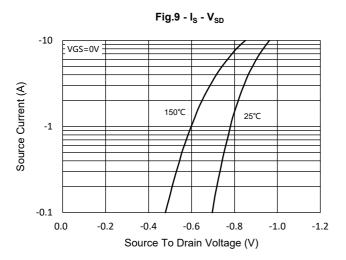
100

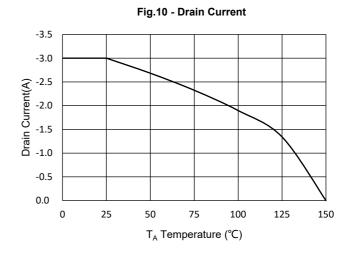
125

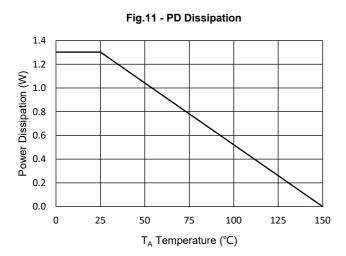
150

T_J - Junction Temperature(°C)











Curve Characteristics

Fig.12 - Safe Operation Area

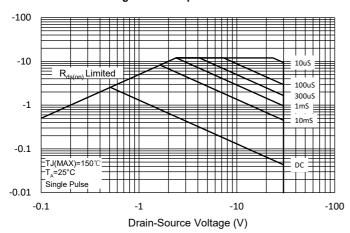
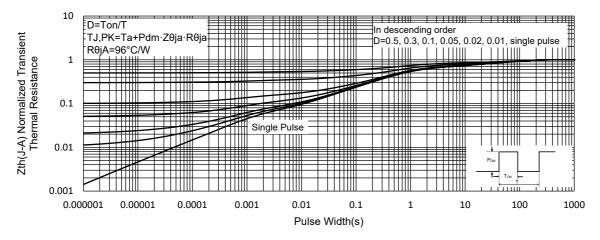


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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